



CENTRIGRID® MAGNETIC LATCHING AEROSPACE RELAY DPDT CMOS COMPATIBLE

SERIES 122C

SERIES DESIGNATION	RELAY TYPE			
122C	DPDT general purpose magnetic latching relay with internal power MOSFET driver and diode coil transient suppression			

DESCRIPTION

The 122C Centigrid magnetic-latching relay is an ultraminiature, hermetically sealed, armature relay capable of being directly driven by most IC logic families. Its low profile height and .100" grid spaced terminals, which precludes the need for spreader pads, make it ideal for applications where extreme packaging density and/or close PC board spacing are required.

The basic concept and internal structure are similar to the Teledyne TO-5 422 relay series. The 122C is capable of meeting Teledyne Relays' T^2R° requirements. The following unique construction features and manufacturing techniques provide overall high reliability and excellent resistance to environmental extremes:

- · All welded construction.
- Unique uni-frame design providing high magnetic efficiency and mechanical rigidity.
- · High force/mass ratios to withstand shock and vibration.
- Advanced cleaning techniques provide maximum assurance of internal cleanliness.
- Precious metal alloy contact material with gold plating assures excellent high current and dry circuit switching capabilities.

The 122C Series utilizes internal silicon diodes for coil suppression, Zener diodes to protect the MOSFET gate inputs, and N-channel enhancement-mode MOSFET chips, which enable direct relay interfacing with most microprocessor and IC logic families (CMOS, TTL and MOS).

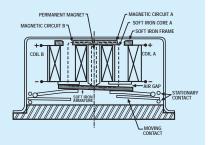
The 122C magnetic-latching relay is ideally suited for applications where power-dissipation must be minimized. The relays can be operated with a short-duration pulse: after contacts have transferred, no external holding power is required.

The magnetic-latching feature of the 122C Series provide a "memory" capability, since the relays will not reset upon removal of power.

By virtue of its inherently low intercontact capacitance and contact circuit losses, the Centigrid relay has shown itself to be an excellent ultraminiature RF switch for frequency ranges well into the UHF spectrum. A typical RF application for the Centigrid® relay is in hand held radio transceivers, wherein the combined features of good RF performance, small size, low coil power dissipation, and high reliability make it a preferred method of transmit-receive switching (see Figure 1).

PRINCIPLE OF OPERATION

Energizing Coil B produces a magnetic field opposing the holding flux of the permanent magnet in Circuit B. As this net holding force decreases, the attractive force in the air gap of Circuit A, which also results from the flux of the permanent magnet, becomes great enough to break the armature free of Core B, and snap it into a closed position against Core A. The armature then remains in this position upon removal of energy from Coil B, but will snap back to position B upon energizing Coil A. Since operation depends upon cancellation of a magnetic field, it is necessary



to apply the correct polarity to the relay coils as indicated on the relay schematic.

When latching relays are installed in equipment, the latch and reset coils should not be pulsed simultaneously. Coils should not be pulsed with less than the maximum set/reset voltage and the pulse width should be a minimum of three times the specified operate time of the relay. If these conditions are not followed, it is possible for the relay to be in the magnetically neutral position.

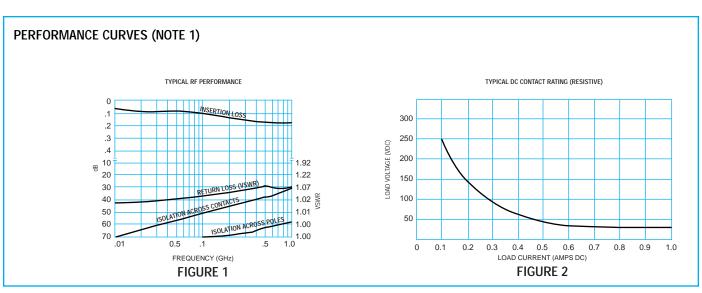
ENVIRONMENTAL AND PHYSICAL SPECIFICATIONS					
Temperature (Ambient)	-65°C to +125°C				
Vibration	30 g's to 3000 Hz (Note 2)				
Shock	100 g's for 6 msec. (Note 2) half-sine				
Acceleration	50 g's (Note 2)				
Enclosure	All welded, hermetically sealed				
Weight	0.10 oz (2.75 gms.) max.				

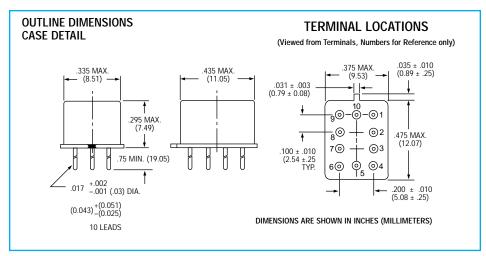
GENERAL ELECTRICAL SPECIFICATIONS $(-65^{\circ}\text{C to } +125^{\circ}\text{C unless otherwise noted})$ (Notes 1 & 6)

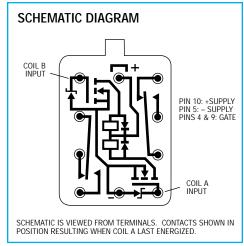
Contact Arrangement		2 Form C (DPDT)				
Rated Duty		Continuous				
Contact Resistance		0.125 ohm max. before life; 0.225 ohm max. after life at 1A/28VDC,				
		(measured 1/8" from header)				
Contact Load Rati (See Fig. 2 for other resistive voltage/cu	er DC	Resistive: 1 Amp/28VDC Inductive: 200 mA/28VDC (320 mH) Lamp: 100 mA/28VDC Low Level: 10 to 50 μA/10 to 50 mV				
Contact Load Rati	ngs (AC)	Resistive: 250 mA/115VAC, 60 and 400Hz (Case not grounded) 100 mA/115VAC, 60 and 400Hz (Case grounded)				
Contact Life Ratings		10,000,000 cycles (typical) at low level 1,000,000 cycles (typical) at 0.5A/28VDC resistive 100,000 cycles min. at all other loads specified above				
Contact Overload Rating		2 A/28VDC Resistive (100 cycles min.)				
Contact Carry Rating		Contact factory				
Operate Time		1.5 msec max. at nominal rated coil voltage at 25°C.				
Minimum Operate Pulse		4.5 msec at nominal voltage.				
Contact Bounce		2.0 msec max.				
Intercontact Capacitance		0.4 pf typical				
Insulation Resistance (Note 4)		10,000 megohms min. between mutually isolated terminals				
Dielectric Strength (Note 4)		Atmospheric pressure: 500 VRMS/60 Hz 70,000 ft.: 125 VRMS/60Hz				
Negative Coil Transient (VDC)		1.0 max.				
Diode P.I.V. (VDC)		100 min.				
Zener Voltage (VDC)		17 min. to 23 max.				
Zener Leakage Current @ 15.2 VDC (µA)		2.5 max.				
Power FET Characteristics -65°C to +125°C	Gate Voltage to Turn Off (Vdc)	0.5 max.				
	Gate Voltage to Turn On (VDC)	3.8 min. (Note 8)				
	Drain-Source Voltage (VDC)	55 max.				

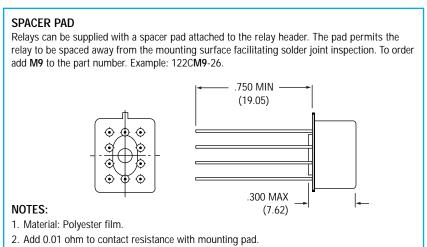
DETAILED ELECTRICAL SPECIFICATIONS (-65°C to +125°C unless otherwise noted) (Note 6)

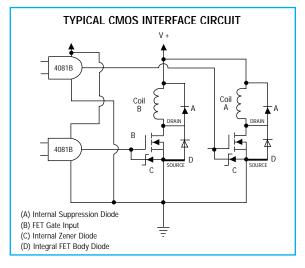
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	BASE PART NUMBERS (Note 3)	122C-5	122C-6	122C-9	122C-12	122C-18	122C-26		
Coil Voltage (VDC)	Nom.	5.0	6.0	9.0	12.0	18.0	26.5		
	Max.	5.6	8.0	12.0	16.0	24.0	32.0		
0.11 0	Max.	114.9	57.0	37.2	27.8	18.2	15.2		
Coil Current (mADC @ 25°C) Note 9	Min.	82.2	41.6	27.4	20.5	13.7	11.4		
Coil Operating Power @ 25°C and Rated Voltage (mW)	Nom.	505	296	288	287	286	351		
Latch and Reset Voltage (VDC) (Note 7)	Max.	3.5	4.5	6.8	9.0	13.5	18.0		











NOTES:

- 1. "Typical" characteristics are based on available data and are best estimates. No on-going verification tests are performed.
- 2. Relay contacts will exhibit no chatter in excess of 10 µsec or transfer in excess of 1 µsec.
- 3. Screened HI-REL versions available. Contact factory.
- 4. Pins 4, 5 and 9 must be shorted when tested for Insulation Resistance and Dielectric Withstanding Voltage.
- 5. Unless otherwise specified, relays will be supplied with either gold plated or solder coated leads. Contact your local representative for ordering information.
- 6. Unless otherwise specified, parameters are initial values.
- 7. The slash and characters appearing after the slash are not marked on the relay.
- 8. Maximum rated gate voltage = 15 VDC.
- 9. Measured for 5 sec max. Includes allowance for "on" resistance of MOSFET.

